

## SLOVENSKI STANDARD oSIST prEN IEC 63550-4:2025

01-november-2025

Polprevodniški elementi - Nevromorfne naprave - 4. del: Metoda ocenjevanja asimetrije v memristorskih napravah

Semiconductor devices - Neuromorphic devices - Part 4: Evaluation method of asymmetry in memristor devices

iTeh Standards

Dispositifs à semiconducteurs - Dispositifs neuromorphiques - Partie 4: Méthode d'évaluation de l'asymétrie des dispositifs à memristance

Ta slovenski standard je istoveten z: prEN IEC 63550-4:2025

ICS:

31.080.99 Drugi polprevodniški elementi Other semiconductor devices

oSIST prEN IEC 63550-4:2025 en

## iTeh Standards (https://standards.iteh.ai) Document Preview

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PROJECT NUMBER: IEC 63550-4 ED1

DATE OF CIRCULATION:

2025-09-05



## 47/2940/CDV

## COMMITTEE DRAFT FOR VOTE (CDV)

CLOSING DATE FOR VOTING:

2025-11-28

	SUPERSEDES DOCUM	MENTS:
	47/2874/CD, 47/2	2928/CC
IEC TC 47 : SEMICONDUCTOR DEVICES		
SECRETARIAT:		SECRETARY:
Korea, Republic of		Mr Cheolung Cha
OF INTEREST TO THE FOLLOWING COMMITTEES:		HORIZONTAL FUNCTION(S):
ASPECTS CONCERNED:		
SUBMITTED FOR CENELEC PARALLEL VOTING ☐ NOT SUBMITTED FOR CENELEC PARALLEL VOTING		
Attention IEC-CENELEC parallel voting / Standards.iteh.ai		
The attention of IEC National Committees, members of CENELEC, is drawn to the fact that this Committee Draft for Vote (CDV) is submitted for parallel voting.		
The CENELEC members are invited to vote through the 163550-4:2025 CENELEC online voting system. ards.iteh.ai/catalog/standards/sist/62b8e9b5-7637-415d-b5b5-abb25449f5b4/osist-pren-iec-63		
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TITLE:  Semiconductor devices - Neuromorphic devices - Part 4: Evaluation method of asymmetry in memristor devices		
PROPOSED STABILITY DATE: 2029		
Note from TC/SC officers:		

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